

30 V, 350 mA N-channel Trench MOSFET

5 November 2022

**Product data sheet** 

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a very small SOT323 (SC70) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- · Very fast switching
- Low threshold voltage
- Trench MOSFET technology
- ESD protection up to 2 kV
- AEC-Q101 qualified

### 3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V
V <sub>GS</sub>	gate-source voltage	_		-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	350	mA
Static chara	acteristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 350 mA; T <sub>j</sub> = 25 °C		-	1	1.4	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



## 5. Pinning information

Table 2. F	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	G	gate	□ 3	D				
2	S	source						
3	D	drain	1 2 SC-70 (SOT323)	G S 017aaa255				

## 6. Ordering information

### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
NX3008NBKW	SC-70	plastic, surface-mounted package; 3 leads; 1.3 mm pitch; 2 mm x 1.25 mm x 0.95 mm body	SOT323		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
NX3008NBKW	AA%

[1] % = placeholder for manufacturing site code

### 8. Limiting values

#### Table 5. Limiting values

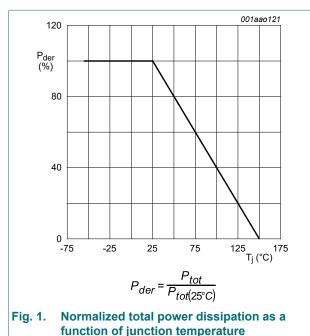
In accordance with the Absolute Maximum Rating System (IEC 60134).

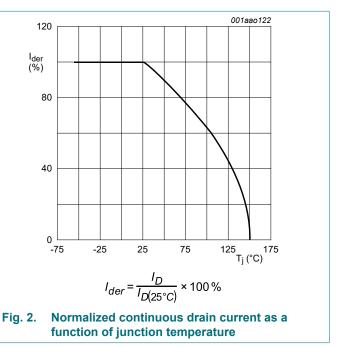
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	350	mA
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	230	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	1.4	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	260	mW
			[1]	-	310	mW
		T <sub>sp</sub> = 25 °C		-	830	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode					
ls	source current	T <sub>amb</sub> = 25 °C	[1]	-	300	mA
ESD maxim	um rating	•				
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[3]	-	2000	V

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

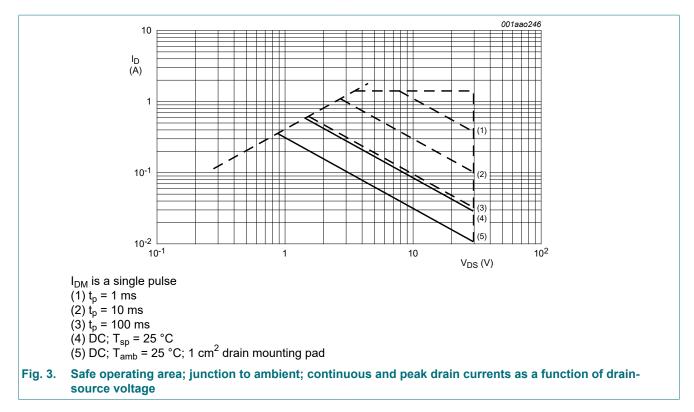
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.





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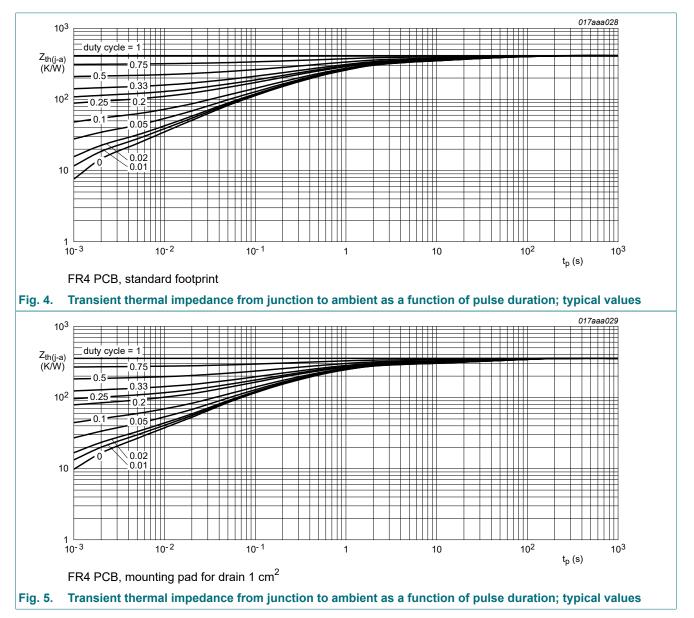


### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient	thermal resistance from	in free air	[1]	-	310	370	K/W
		[2]	-	260	300	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	115	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

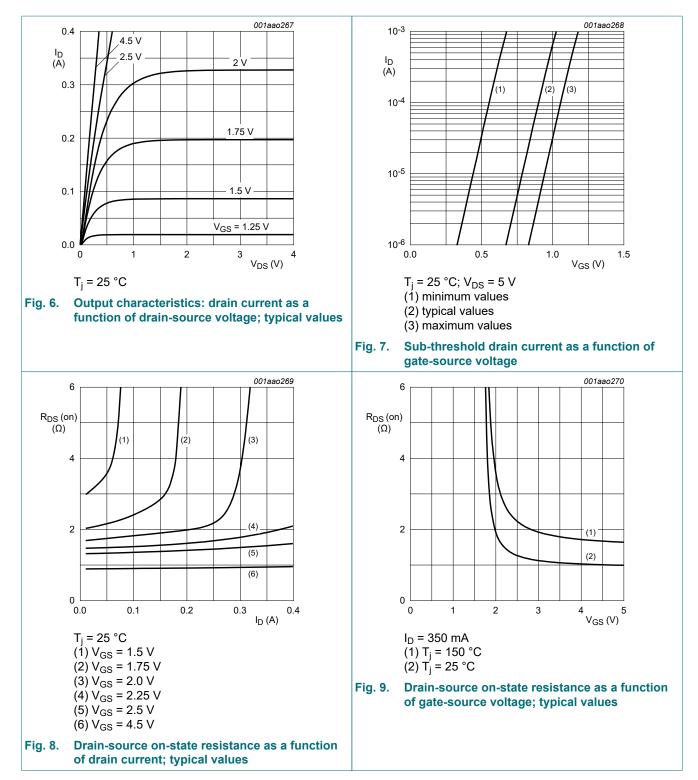
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.



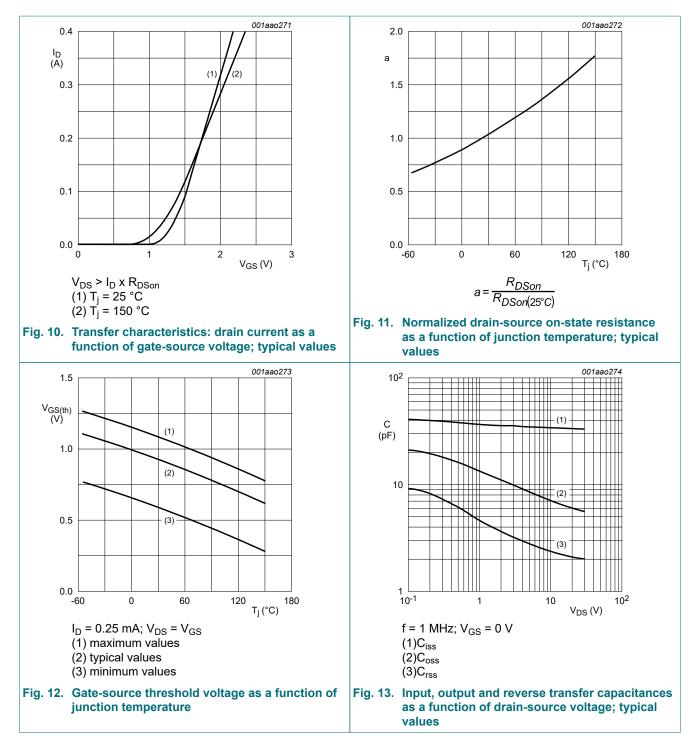
## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = 250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	0.6	0.9	1.1	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
		V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	10	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.2	1	μA
		V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.2	1	μA
		V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	10	-	nA
		V <sub>GS</sub> = -4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	10	-	nA
		V <sub>GS</sub> = 2.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	1	-	nA
		V <sub>GS</sub> = -2.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	1	-	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 350 mA; T <sub>j</sub> = 25 °C	-	1	1.4	Ω
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 350 mA; T <sub>j</sub> = 150 °C	-	1.8	2.5	Ω
		V <sub>GS</sub> = 2.5 V; I <sub>D</sub> = 200 mA; T <sub>j</sub> = 25 °C	-	1.4	2.1	Ω
		V <sub>GS</sub> = 1.8 V; I <sub>D</sub> = 10 mA; T <sub>j</sub> = 25 °C	-	2	2.8	Ω
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 350 mA; T <sub>j</sub> = 25 °C	-	310	-	mS
Dynamic ch	aracteristics	· · · · · · · · · · · · · · · · · · ·	·	·		
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 15 V; I <sub>D</sub> = 350 mA; V <sub>GS</sub> = 4.5 V;	-	0.52	0.68	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.17	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.08	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	34	50	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	6.5	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	2.2	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 20 V; $R_{L}$ = 250 $\Omega$ ; $V_{GS}$ = 4.5 V;	-	15	30	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	11	-	ns
t <sub>d(off)</sub>	turn-off delay time	] [	-	69	138	ns
łf	fall time	] [	-	19	-	ns
Source-drai	n diode	· ·				
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 350 mA; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	0.47	0.85	1.2	V

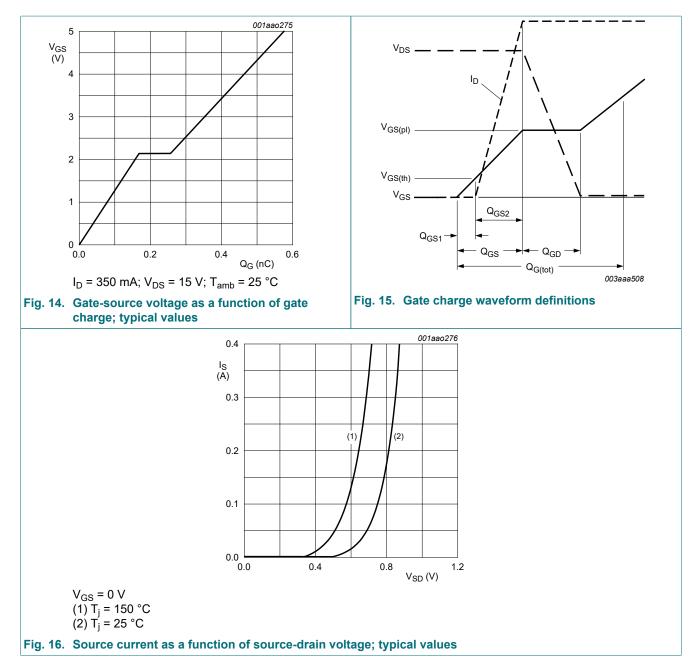
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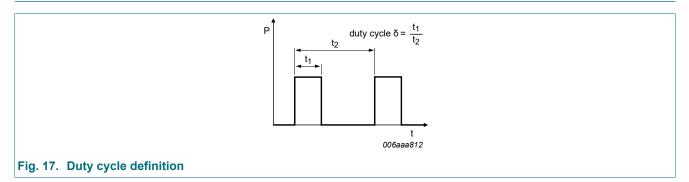
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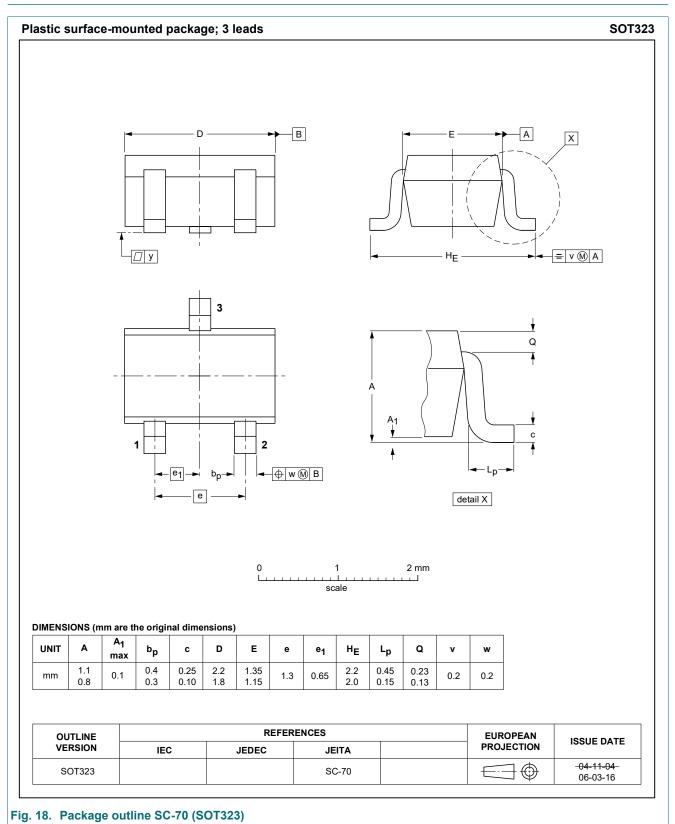
### **11. Test information**



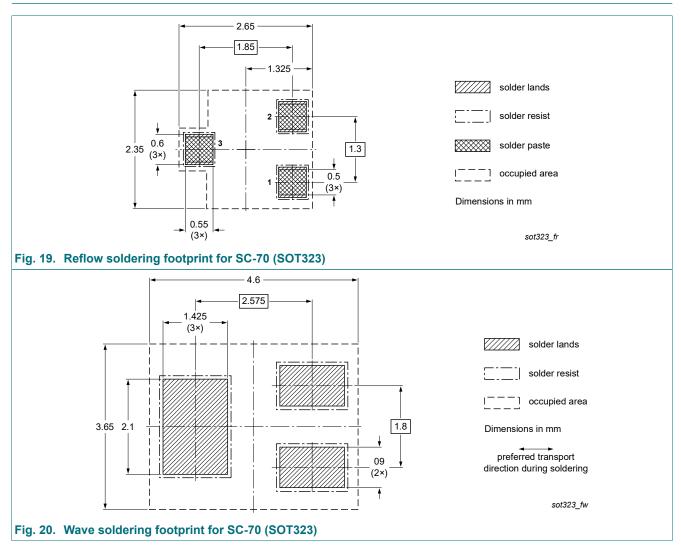
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline



### 13. Soldering



**Product data sheet** 

# 14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
NX3008NBKW v.2	20221105	Product data sheet	-	NX3008NBKW v.1			
Modifications:	Chapter "Characteristics": typo correction, V <sub>SD</sub> axis scaling for Fig. 16 revised						
NX3008NBKW v.1	20110802	Product data sheet	-	-			

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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